

Compensating for diode drop variations



John Betten

As useful as the rectification properties of diodes are, the forward voltage drop they create can vary widely with temperature. This increases losses and can introduce tolerance errors in power supplies.

While it may not be possible to eliminate their losses, it is possible to use diodes in ways that can reduce tolerance errors in certain applications. This article will provide three examples that will show you how to achieve this.

You can build a simple low-current voltage regulator from a resistor and a Zener diode. This type of regulator is often adequate for noncritical applications such as internal bias voltages. The circuit generally regulates the output voltage to about $\pm 10\%$ tolerance. However, it may be possible to improve the regulation by adding a diode in series.

Figure 1 shows the addition of a diode in series with the Zener diode. The curve in Figure 1 plots the temperature coefficient for various Zener voltages. Above values of 4.7V, the temperature coefficient becomes increasingly positive, so as the operating temperature increases, the voltage across the Zener diode increases. If paired with the negative temperature coefficient of a diode, the increase of the Zener voltage will be offset in part by the decrease in the diode forward voltage, resulting in temperature error cancellation.

Zener values below 4.7V have a negative temperature coefficient, so adding a diode in series would actually increase regulation errors.

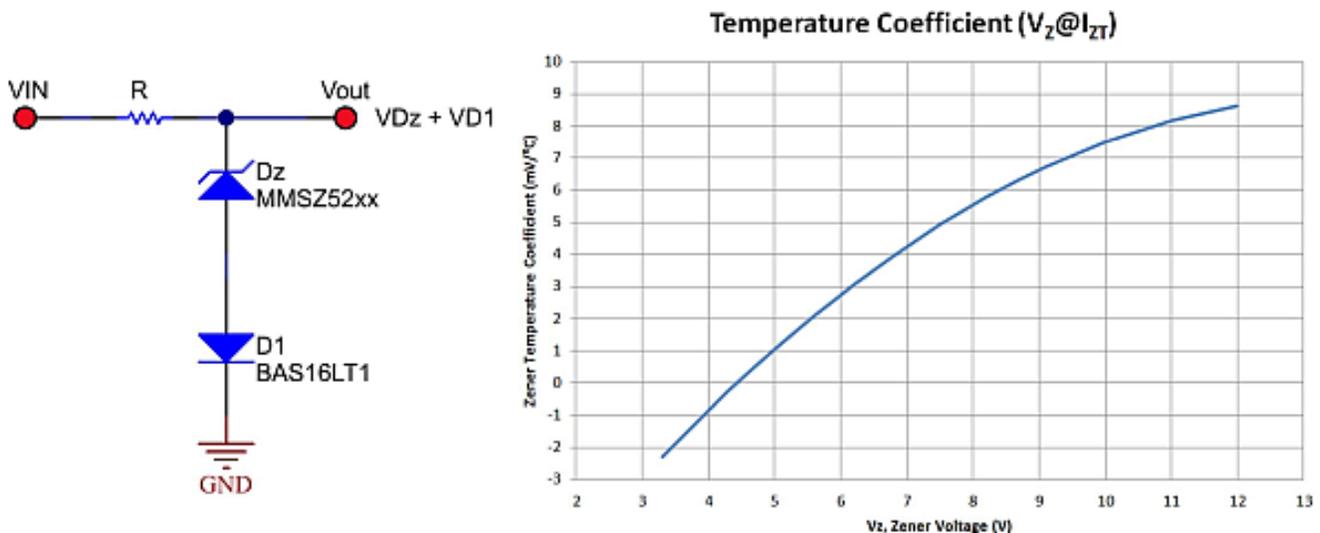


Figure 1. A positive-temperature coefficient Zener diode in series with a negative-temperature coefficient diode can reduce temperature errors.

As an example, a 7.5V Zener diode shows a temperature coefficient of $+5\text{mV}/^\circ\text{C}$, while a conventional diode (BAT16) is about $-1.6\text{mV}/^\circ\text{C}$ at 10mA. This value becomes increasingly more negative ($-3\text{mV}/^\circ\text{C}$) with very small diode currents, so be sure to check it at the current level of the Zener diode. Ideally, the two temperature coefficients would perfectly cancel out, but that is not realistic or always necessary, as a simple improvement may be sufficient. For higher-voltage Zener diodes with even higher positive-temperature coefficients, two (or more) diodes could improve cancellation.

Figure 2 shows the calculated voltage regulation error of Figure 1 versus the output voltage for various Zener values – without series diodes, with one series diode and with two series diodes – operating between 25° C and 100° C. The vertical line in Figure 2 shows that adding series diodes can reduce temperature-dependent errors by 3-5% for a 7.5V output.

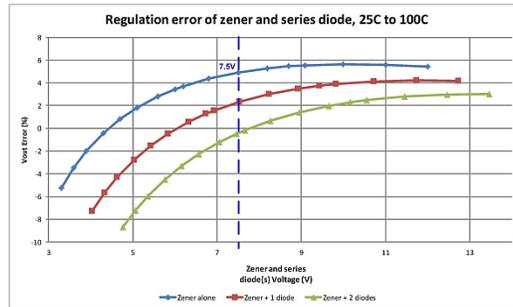


Figure 2. Adding one or more diodes in series with a Zener value over 4.7V reduces voltage regulation errors.

The second example involves converters that require a level shifter to send the output voltage information to the control circuit.

Figure 3 is a negative-input to positive-output inverting buck-boost. The control circuit is referenced to the $-V_{in}$ rail, but the output voltage is referenced to GND. For the control circuit to accurately regulate the output voltage, the level shifter recreates the differential “Vout to GND” voltage between “FB and $-V_{in}$.” In this implementation, a current source approximately equal to $(V_{out} - V_{be Q1})/R$ flows from Vout to $-V_{in}$. This current flows in the lower resistor to reconstruct the output voltage referenced to $-V_{in}$. Adding Q2, configured as a diode, restores the V_{be} drop lost from Q1. The level-shifted voltage at the FB pin now closely replicates that between Vout and GND, except for a small error related to beta.

One benefit of adding “diode” Q2 is that its forward voltage will be quite close to that of Q1, since almost the exact same current flows through both. To achieve the best voltage matching on Q2, you should use the same transistor as Q1. Another benefit is that both transistors have the same temperature coefficients, allowing their forward voltages to track each other more precisely. The temperature error associated with V_{be} variations are significantly reduced since they cancel each other out ($V_{FB} \sim V_{out} - V_{be Q1} + V_{be Q2}$). It’s important to locate the Q1 and Q2 near each other so that they are exposed to the same temperature, or if possible, to use a dual-transistor package.

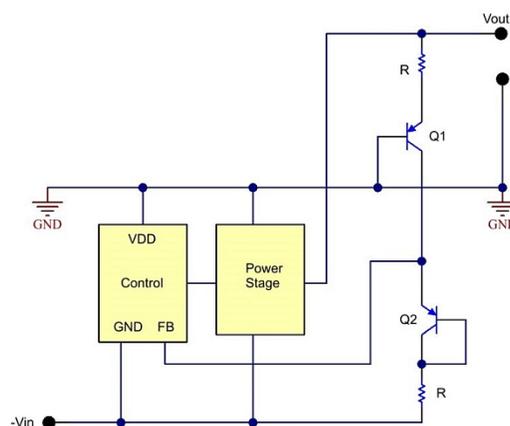


Figure 3. A level shifter implements Q2 to cancel variations related to Q1.

The third example shown in Figure 4 shows a boost converter with a series of charge-pump stages, where each stage “n” adds approximately “V1” to the total output at “Vn + 1.” For more details on voltage multiplier operation, see “Power Tips: Multiply your output voltage.”

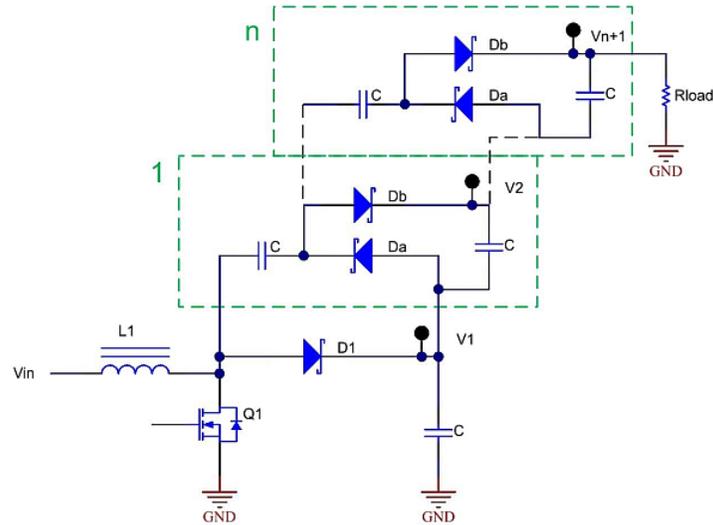


Figure 4. Charge-pump diode drops can offset each other.

Equation 1 approximates the total output voltage as:

$$V_{n+1} \sim (n+1) \times V1 + n \left(V_{D1} - V_{Da} - V_{Db} - \frac{I_{load}}{f_{sw} \times C} \right), \quad n = \text{charge pump stages} \quad (1)$$

From Equation 1, you can see that V_{n+1} is largely determined by multiples of n , but reduced by the “error terms” related to diode forward drops and the charge-pump transfer capacitor’s ripple voltage. Assuming that all diodes are the same type and that their forward voltages are equal:

$V_{D1} = V_{Da} = V_{Db}$, then Equation 2 is:

$$V_{n+1} \sim (n+1) \times V1 - n \left(V_{D1} + \frac{I_{load}}{f_{sw} \times C} \right) \quad (2)$$

In Equation 2, the “error terms” on the right side reduce the output below its ideal $n+1$ multiple. To improve this, using Schottky diodes for V_{Da} and V_{Db} and a conventional diode for V_{D1} , with forward voltage drops equal:

$V_{Da} = V_{Db} = V_{D1} / 2$, then Equation 3 is:

$$V_{n+1} \sim (n+1) \times V1 - n \left(\frac{I_{load}}{f_{sw} \times C} \right) \quad (3)$$

From Equation 3, you can see that it is possible to reduce the error terms associated with the diode drops, thereby increasing the output voltage further. While Equation 3 is still an approximation, the concept is valid in that the output voltage will increase.

Diode forward voltage and temperature variations often degrade circuit performance, but that doesn’t always have to be the case. These design examples demonstrate methods in which it’s possible to cancel or minimize the temperature-dependent characteristics of diodes.

Check out TI’s [Power Tips blog series](#) on Power House.

Also see :

- [Easily measure diode capacitance and reverse recovery](#)
- [Power Tips #79: Load transient testing with high slew rates](#)

Previously published on [EDN.com](#).

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2024, Texas Instruments Incorporated